NSN 5961-01-115-8267

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-115-8267 **Inclosure Material:** Metal **Overall Length:** 0.375 inches Overall Diameter: 0.875 inches **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open and 60.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 7.00 amperes all primaries and 30.00 amperes all primaries **Power Rating Per Characteristic:** 6.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 81349-mil-s-19500/433 government specification Shelf Life: N/a **Unit Of Measure:** Demilitarization: No